

2.0kV 2.0A HIGH VOLTAGE DIODES

BR2 is high reliability resin molded type high voltage diode in small size package which is sealed a multilayed mesa type silicon chip by epoxy resin.

■ Features

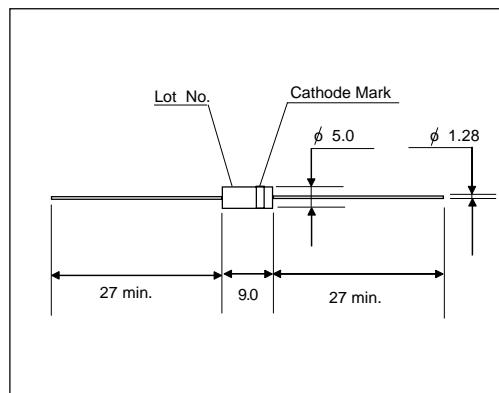
- High speed switching
- High Current
- High surge resistivity for CRT discharge
- High reliability design
- High Voltage

■ Applications

- X light Power supply
- Laser
- Voltage doubler circuit
- Microwave emission power

■ Maximum Ratings and Characteristics

- Absolute Maximum Ratings

■ Outline Drawings : mm**■ Cathode Mark**

Type	Mark
BR2	

Items	Symbols	Condition	BR2	Units
Repetitive Peak Reverse Voltage	V_{RRM}		2.0	kV
Average Output Current	I_o	$T_a=25^\circ C$, Resistive Load	2.0	A _{peak}
Surge Current	I_{FSM}		40	A _{peak}
Junction Temperature	T_j		155	°C
Allowable Operation Case Temperature	T_c		125	°C
Storage Temperature	T_{stg}		-40 to +155	°C

- Electrical Characteristics ($T_a=25^\circ C$ Unless otherwise specified)

Items	Symbols	Conditions	BR2	Units
Maximum Forward Voltage Drop	V_F	at $25^\circ C$, $I_F = I_{F(AV)}$	2.4	V
Maximum Reverse Current	I_{R1}	at $25^\circ C$, $V_R = V_{RRM}$	3.0	uA
	I_{R2}	at $100^\circ C$, $V_R = V_{RRM}$	30	uA
Maximum Reverse Recovery Time	T_{rr}	at $25^\circ C$	--	nS
Junction Capacitance	C_j	at $25^\circ C$, $V_R=0V$, $f=1MHz$	--	pF